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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR $\mu PA1808$

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

ÅННĂ

DESCRIPTION

The μ PA1808 is a switching device, which can be driven directly by a 4.0 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as DC/DC converters and power management of notebook computers and so on.

FEATURES

- 4.0 V drive available
- Low on-state resistance
- Built-in G-S protection diode against ESD

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1808GR-9JG	Power TSSOP8

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V
Gate to Source Voltage ($V_{DS} = 0 V$)	Vgss	±20	V
Drain Current (DC) (T _A = 25°C)	D(DC)	±9.5	Α
Drain Current (pulse) Note1	D(pulse)	±38	Α
Total Power Dissipation Note2	Рт	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C

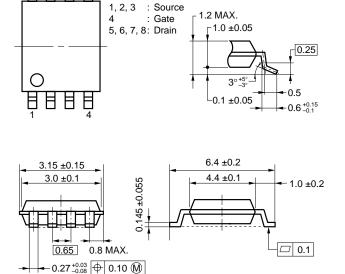
Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- 2. Mounted on ceramic substrate of 5000 mm² x 1.1 mm
- **Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

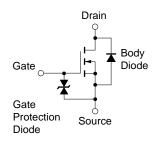
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PACKAGE DRAWING (Unit: mm)



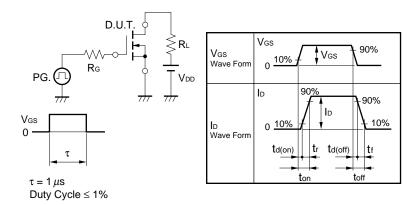
EQUIVALENT CIRCUIT



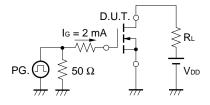
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	ldss	Vds = 30 V, Vgs = 0 V			1.0	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 18 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	VGS(off)	V _{DS} = 10 V, I _D = 1.0 mA	1.5	1.9	2.5	V
Forward Transfer Admittance	yfs	Vds = 10 V, Id = 5.0 A	5.0	10.5		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 5.0 A		13.5	17	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 5.0 A		17	23	mΩ
	RDS(on)3	Vgs = 4.0 V, Id = 5.0 A		19	26	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		660		pF
Output Capacitance	Coss	Vgs = 0 V		280		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		100		pF
Turn-on Delay Time	td(on)	Vdd = 15 V, Id = 5.0 A		13.5		ns
Rise Time	tr	V _{GS} = 10 V		5.6		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		38		ns
Fall Time	tr			7.9		ns
Total Gate Charge	QG	V _{DD} = 24 V		13		nC
Gate to Source Charge	QGS	V _{GS} = 10 V		1.8		nC
Gate to Drain Charge	Qgd	ID = 9.5 A		3.7		nC
Body Diode Forward Voltage	VF(S-D)	IF = 9.5 A, VGS = 0 V		0.84		V
Reverse Recovery Time	trr	IF = 9.5 A, VGS = 0 V		27		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		19		nC

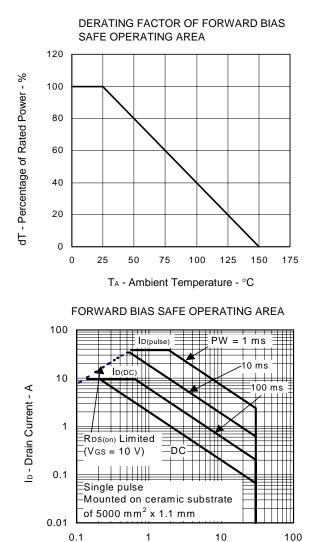
TEST CIRCUIT 1 SWITCHING TIME



TEST CIRCUIT 2 GATE CHARGE

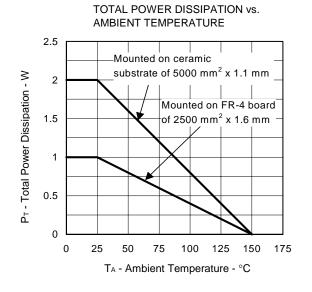


TYPICAL CHARACTERISTICS (TA = 25°C)

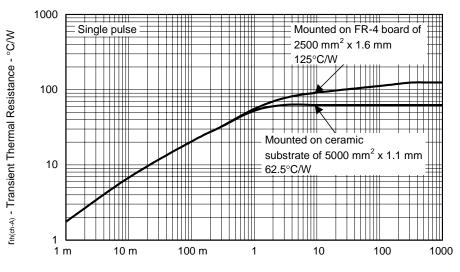




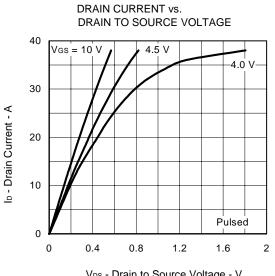
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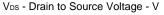


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

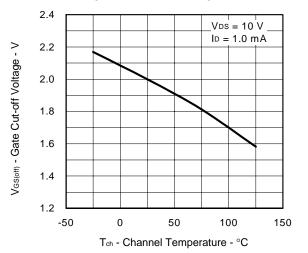


PW - Pulse Width - s

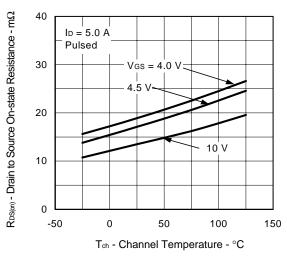




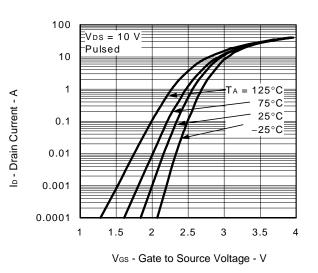




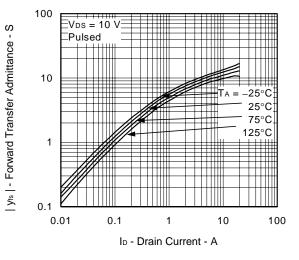
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



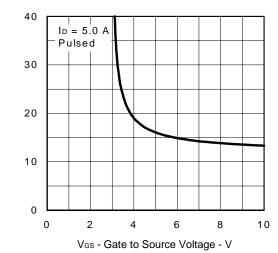
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

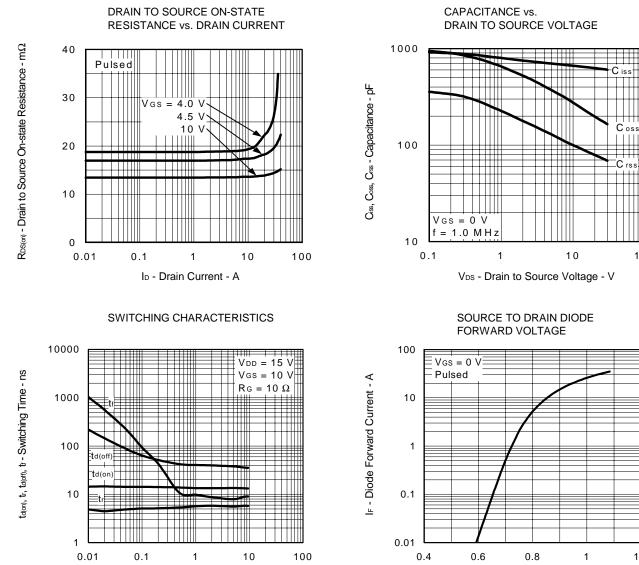


 $R_{DS(m)}$ - Drain to Source On-state Resistance - $m\Omega$

100

1.2

VF(S-D) - Source to Drain Voltage - V

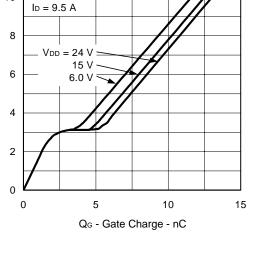


I₀ - Drain Current - A

V_{Gs} - Gate to Source Voltage - V

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